

# **Standard Rectifier Module**

= 2x 1600 V

190 A

 $V_{\mathsf{F}}$ 0.96 V

# Phase leg

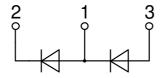
#### Part number

#### MDD172-16N1



Backside: isolated





## Features / Advantages:

- Package with DCB ceramic
- Improved temperature and power cycling
- Planar passivated chips
- Very low forward voltage drop
- Very low leakage current

## **Applications:**

- Diode for main rectification
- For single and three phase bridge configurations
- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

## Package: Y4

- Isolation Voltage: 3600 V~
- Industry standard outline
- RoHS compliant
- Soldering pins for PCB mounting
- Base plate: DCB ceramic
- Reduced weight
- Advanced power cycling

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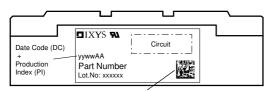


Rectifier	Rectifier			Ratings				
Symbol	Definition	Conditions		min.	typ.	max.	Unit	
V <sub>RSM</sub>	max. non-repetitive reverse bloc	cking voltage	$T_{VJ} = 25^{\circ}C$			1700	V	
V <sub>RRM</sub>	max. repetitive reverse blocking	voltage	$T_{VJ} = 25^{\circ}C$			1600	V	
I <sub>R</sub>	reverse current	V <sub>R</sub> = 1600 V	$T_{VJ} = 25^{\circ}C$			1	mA	
		$V_R = 1600 \text{ V}$	$T_{VJ} = 150$ °C			20	mΑ	
V <sub>F</sub>	forward voltage drop	I <sub>F</sub> = 150 A	$T_{VJ} = 25^{\circ}C$			1.07	V	
		$I_F = 300 A$				1.22	٧	
		I <sub>F</sub> = 150 A	T <sub>VJ</sub> = 125°C			0.96	V	
		$I_F = 300 A$				1.16	٧	
I FAV	average forward current	T <sub>C</sub> = 100°C	$T_{VJ} = 150$ °C			190	Α	
I <sub>F(RMS)</sub>	RMS forward current	180° sine				300	Α	
V <sub>F0</sub>	threshold voltage $T_{vJ} = 150^{\circ}$					0.80	٧	
r <sub>F</sub>	slope resistance } for power	loss calculation only				0.8	mΩ	
R <sub>thJC</sub>	thermal resistance junction to ca	ase				0.21	K/W	
R <sub>thCH</sub>	thermal resistance case to heats	sink			0.08		K/W	
P <sub>tot</sub>	total power dissipation		$T_{C} = 25^{\circ}C$			600	W	
I <sub>FSM</sub>	max. forward surge current	t = 10 ms; (50 Hz), sine	$T_{VJ} = 45^{\circ}C$			6.60	kA	
		t = 8,3  ms; (60 Hz), sine	$V_R = 0 V$			7.13	kA	
		t = 10 ms; (50 Hz), sine	T <sub>vJ</sub> = 150°C			5.61	kA	
		t = 8,3  ms; (60 Hz), sine	$V_R = 0 V$			6.06	kA	
l²t	value for fusing	t = 10 ms; (50 Hz), sine	$T_{VJ} = 45^{\circ}C$			217.8	kA2s	
		t = 8,3 ms; (60 Hz), sine	$V_R = 0 V$			211.5	kA2s	
		t = 10 ms; (50 Hz), sine	$T_{VJ} = 150$ °C			157.4	kA2s	
		t = 8.3  ms; (60 Hz), sine	$V_R = 0 V$			152.8	kA2s	
CJ	junction capacitance	$V_{R} = 400 \text{ V}; f = 1 \text{ MHz}$	$T_{VJ} = 25^{\circ}C$		238		pF	





Package	Package Y4			Ratings				
Symbol	Definition	Conditions			min.	typ.	max.	Unit
I <sub>RMS</sub>	RMS current	per terminal					300	Α
T <sub>VJ</sub>	virtual junction temperature	,			-40		150	°C
Top	operation temperature				-40		125	°C
T <sub>stg</sub>	storage temperature						125	°C
Weight						150		g
M <sub>D</sub>	mounting torque				2.25		2.75	Nm
$\mathbf{M}_{\scriptscriptstyleT}$	terminal torque				4.5		5.5	Nm
d <sub>Spp/App</sub>	oroonaga diatanaa an aurfa	and latriking distance through air	terminal to terminal	14.0	10.0			mm
d <sub>Spb/Apb</sub>	creepage distance on suria	ce   striking distance through air	terminal to backside	16.0	16.0			mm
V <sub>ISOL</sub>	isolation voltage	t = 1 second	50/60 Hz, RMS; IsoL ≤ 1 mA		3600			V
.002		t = 1 minute			3000			٧



Data Matrix: part no. (1-19), DC + PI (20-25), lot.no.# (26-31), blank (32), serial no.# (33-36)

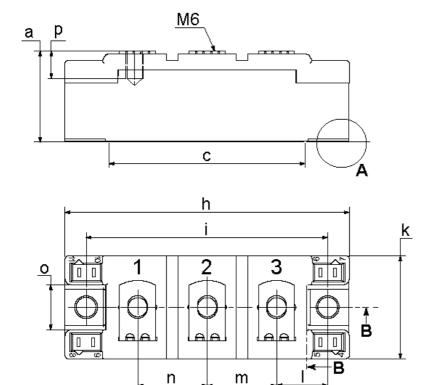
Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	MDD172-16N1	MDD172-16N1	Box	6	429724

<b>Equivalent Circuits for Simulation</b>			* on die level	$T_{VJ} = 150^{\circ}C$
$I \rightarrow V_0$	)—R <sub>o</sub>	Rectifier		
V <sub>0 max</sub>	threshold voltage	8.0		V
R <sub>0 max</sub>	slope resistance *	0.4		mΩ

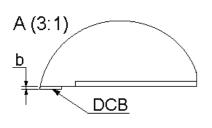


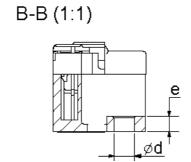


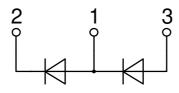
## Outlines Y4



Dim.	MIN	MAX	MIN	MAX	
Diiii.	[mm]	[mm]	[inch]	[inch]	
а	30.0	30.6	1.181	1.205	
b	typ.	0.25	typ. ۱	0.010	
С	64.0	65.0	2.520	2.559	
d	6.5	7.0	0.256	0.275	
е	4.9	5.1	0.193	0.201	
h	93.5	94.5	3.681	3.720	
i	79.5	80.5	3.130	3.169	
k	33.4	34.0	1.315	1.339	
-	16.7	17.3	0.657	0.681	
m	22.7	23.3	0.894	0.917	
n	22.7	23.3	0.894	0.917	
0	14.0	15.0	0.551	0.591	
р	typ.	10.5	typ. 0.413		

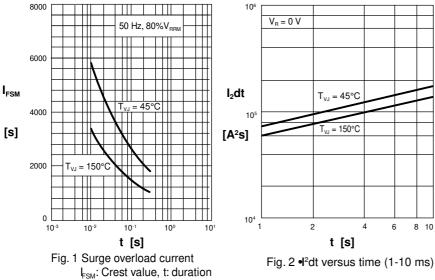








#### Rectifier



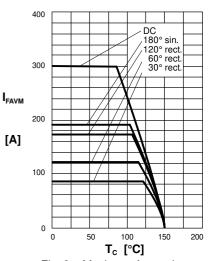


Fig. 2a Maximum forward current at case temperature

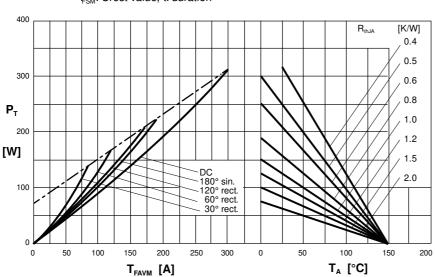
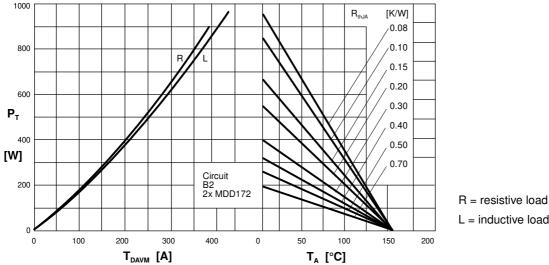


Fig. 3 Power dissipation vs. forward current and ambient temperature (per diode)



L = inductive load

Fig. 4 Single phase rectifier bridge: Power dissipation vs. direct output current and ambient



#### Rectifier

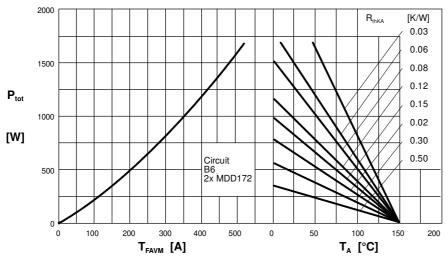


Fig. 5 Three phase rectifier bridge: Power dissipation vs. direct output current and ambient temperature

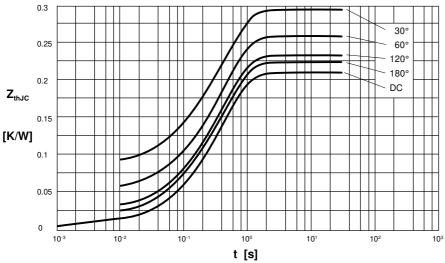


Fig. 6 Transient thermal impedance junction to case (per diode)

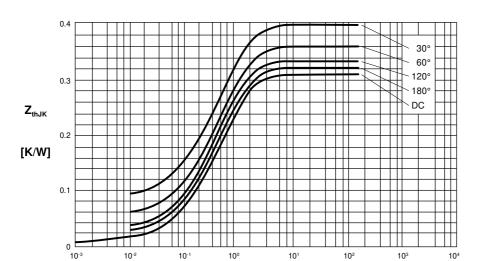


Fig. 7 Transient thermal impedance junction to heatsink (per diode)

t [s]

 $R_{thJC}$  for various conduction angles d:

d	$\mathbf{R}_{thJC}\left[K/W\right]$
DC	0.210
180°	0.223
120°	0.233
60°	0.260
30°	0.295

Constants for  $Z_{\text{\tiny thJC}}$  calculation:

i	$\mathbf{R}_{thi}  [K/W]$	<b>t</b> <sub>i</sub> [s]
1	0.0087	0.001
2	0.0163	0.065
3	0.1850	0.400

R<sub>thJK</sub> for various conduction angles d:

d	$\mathbf{R}_{thJK}  [K/W]$
DC	0.310
180°	0.323
120°	0.333
60°	0.360
30°	0.395

Constants for  $Z_{thJK}$  calculation:

i	$R_{thi}$ [K/W]	t <sub>i</sub> [s]
1	0.0087	0.001
2	0.0163	0.065
3	0.1850	0.400
4	0.1000	1.290

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<u>25.163.2453.0</u> <u>25.16</u>	63.4253.0 25.	190.2053.0	25.194.3453.0	25.320.4853.1	25.320.5253.1	25.326.3253.1	25.326.3553.1	25.330.1653.1
<u>25.330.4753.1</u> <u>25.33</u>	30.5253.1 25	334.3253.1	25.334.3353.1	25.350.2053.0	25.352.4753.1	25.522.3253.0	<u>T483C</u> <u>T484C</u>	<u>T485F</u> <u>T485H</u>
T512F-YEB T513F	T514F T554	<u>T612FSE</u>	25.161.3453.0	25.179.2253.0	25.194.3253.0	25.325.1253.1	25.326.4253.1	25.330.0953.1
<u>25.332.4353.1</u> <u>25.33</u>	50.1653.0 25	350.2453.0	25.352.1453.0	25.352.1653.0	25.352.2453.0	25.352.5453.1	25.522.3353.0	25.602.4053.0
25.640.5053.0								